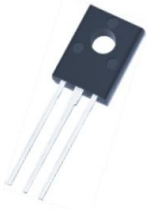
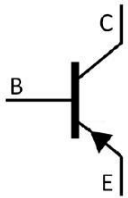


TO-126F PNP Silicon PNP transistor in a TO-126F Plastic Package.

- MJE200

Low collector-emitter saturation voltage, high current gain bandwidth product, Complement to MJE200.

Designed for general audio amplifier applications.

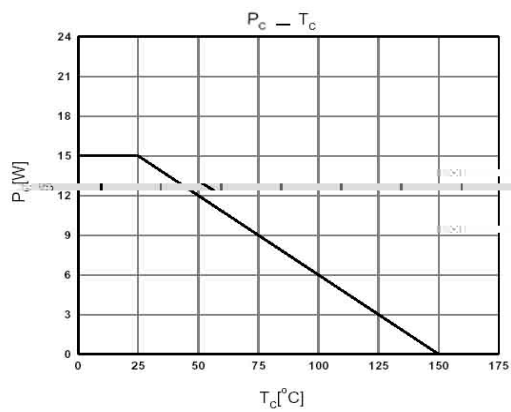
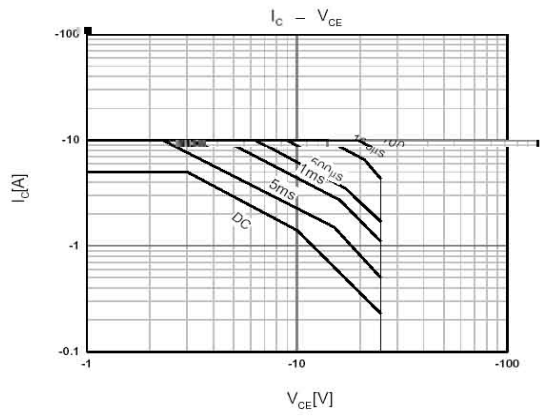
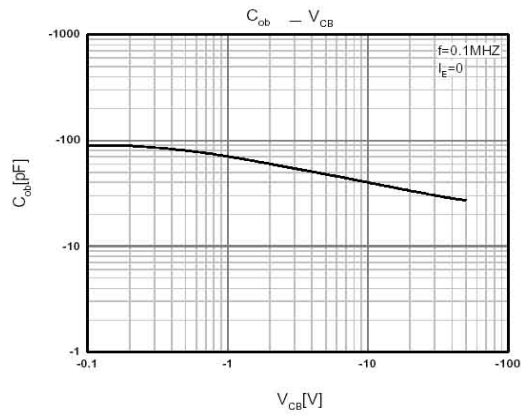
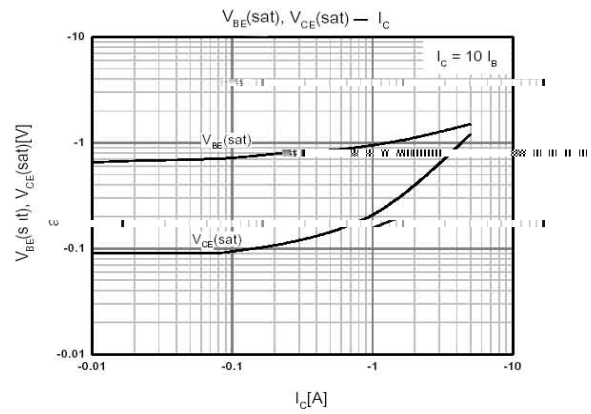
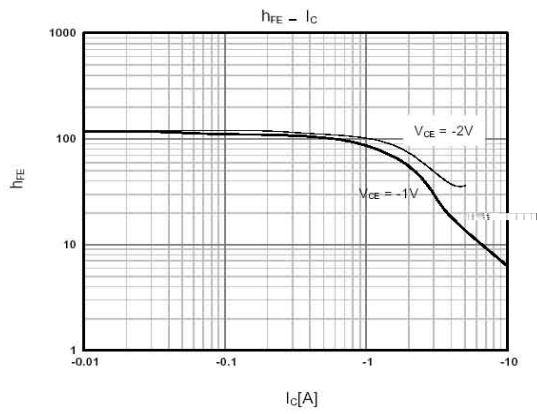


PIN1 Emitter PIN 2 Collector PIN 3 Base

。 See Marking Instructions.

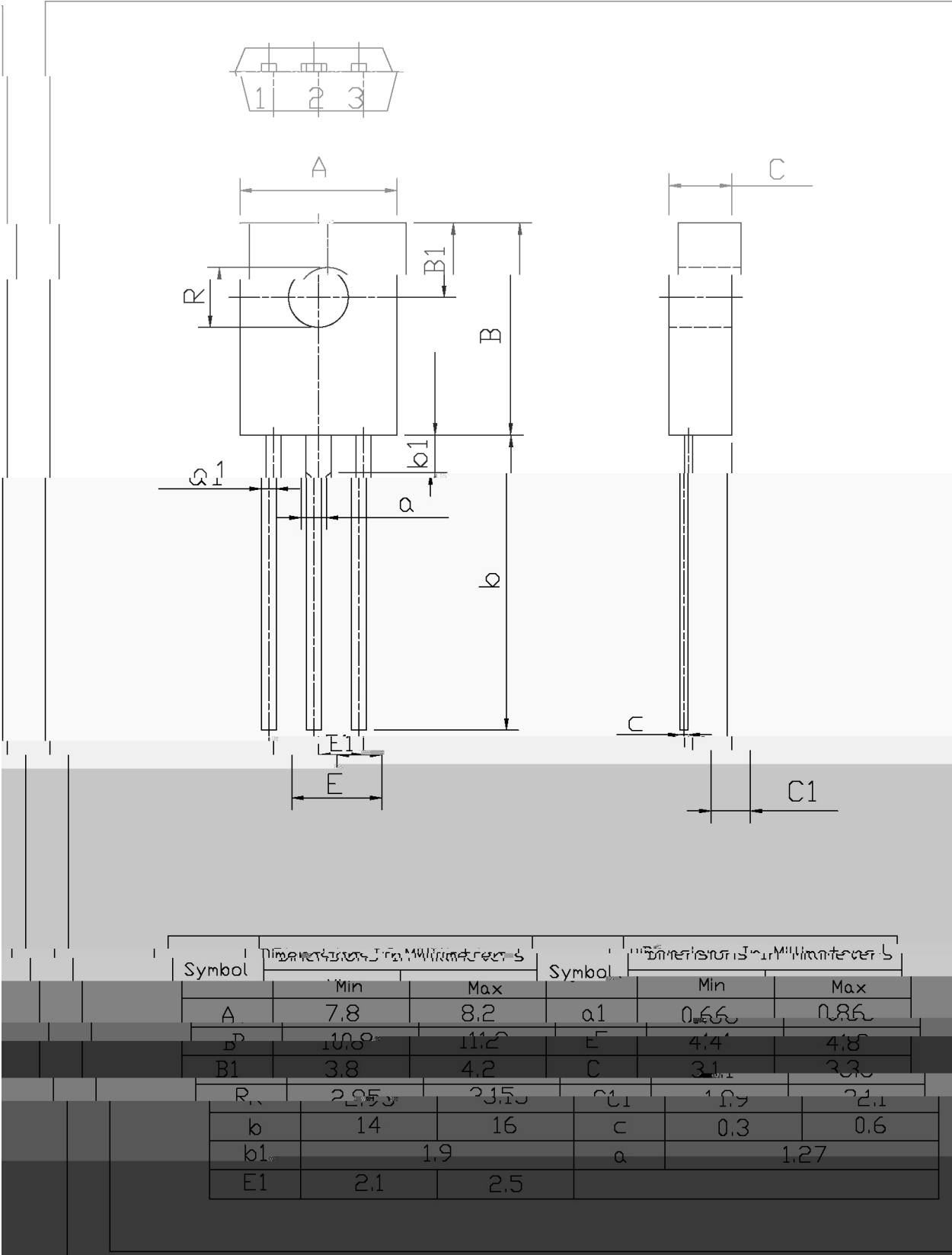
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-40	V
Collector to Emitter Voltage	V_{CEO}	-25	V
Emitter to Base Voltage	V_{EBO}	-8.0	V
Collector Current - Continuous	I_C	-5.0	A
Collector Power Dissipation	$P_C(T_C=25^{\circ}\text{C})$	15	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55~150	

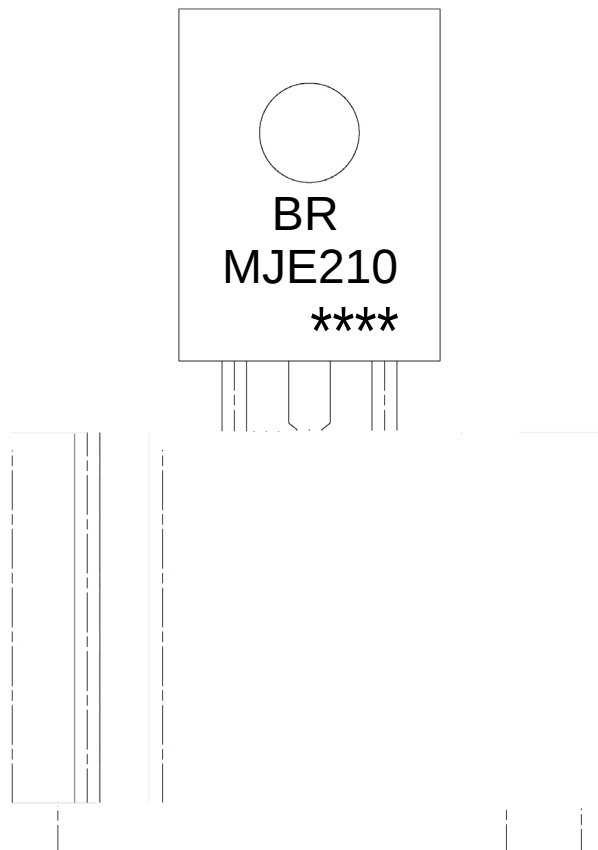
Parameter



TU-126T

单位: mm





BR

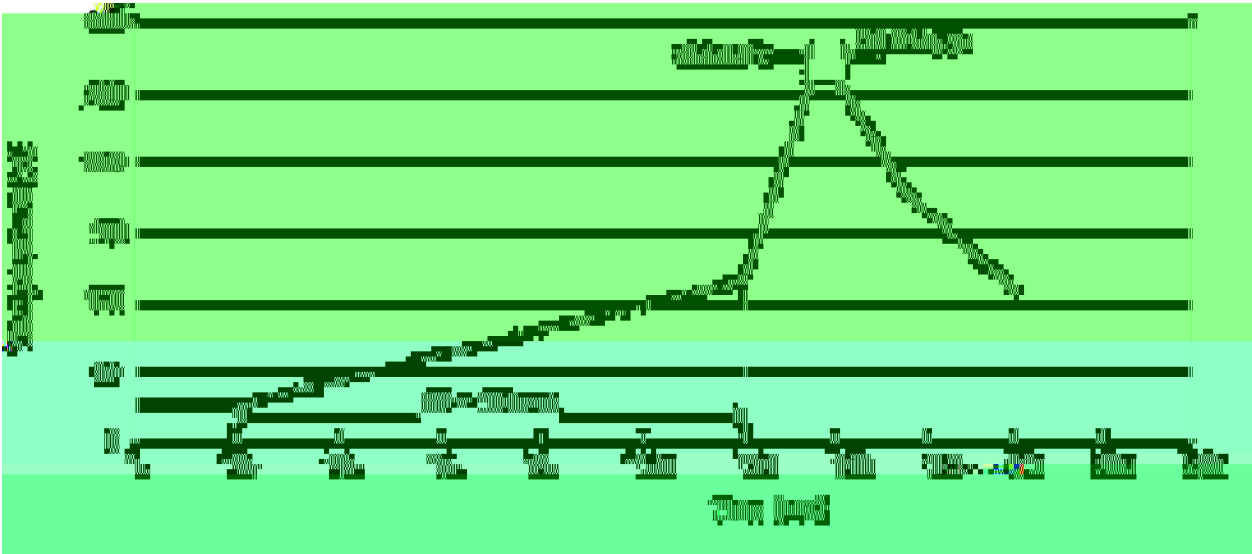
MJE210

Note:

BR: Company Code

MJE210: Product Type.

****: Lot No. Code, code change with Lot No.



Note:

- 1

25 150

60 90sec;

2

255±5

5±0.5sec;

3

2 10

/sec.
- 1.Preheating:25~150

,

Time:60~90sec.

2.Peak Temp.:255±5

,

Duration:5±0.5sec.

3. Cooling Speed: 2~10

/sec.

270±5

10±1 sec.

Temp.:270±5

Time:10±1 sec

/ BULK

Package Type	Units					Dimension (unit mm ³)		
	Units/Tube /	Tubes/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Tube	Inner Box	Outer Box
TO-126/F	500	6	3,000	5	15,000	135×190	237×172×102	560×245×195

/ TUBE

Package Type	Units					Dimension (unit mm ³)		
	Units/Tube /	Tubes/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Tube	Inner Box	Outer Box
TO-126/F	65	26	1,690	5	8,450	532×31×5.6	555×164×50	575×290×180